

# FRED

## Ultrafast Soft Recovery Diode

### 200A / 600V



#### FEATURES

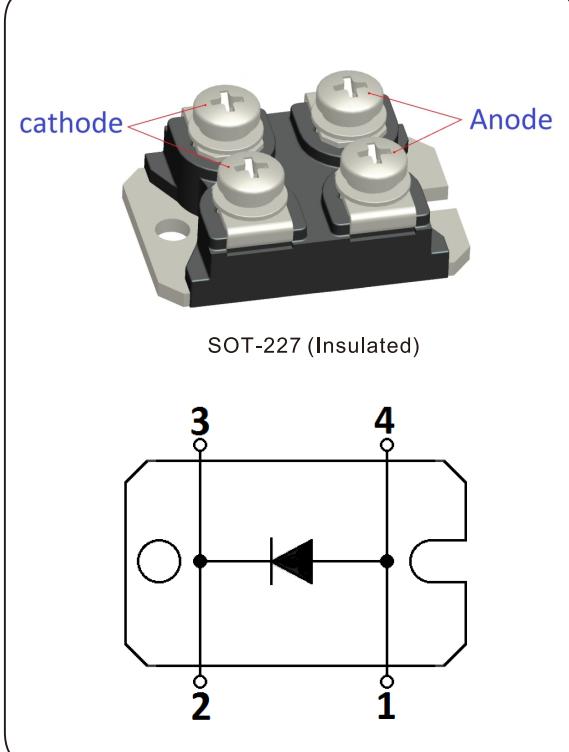
- Fast recovery time characteristic
- Electrically isolated base plate
- Large creepage distance between terminal
- Simplified mechanical designs, rapid assembly
- Compliant to RoHS
- Designed and for industrial level
- Planar passivated chips

#### DESCRIPTION

This SOT-227 modules with FRED rectifier are available in single diode configuration. The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

#### APPLICATIONS

- Switching power supplies
- Inverters
- Motor controllers
- Converters
- Snubber diodes
- Uninterruptible power supplies (UPS)
- Induction heating
- High speed rectifiers
- Free wheeling diodes
- DC choppers



#### PRODUCT SUMMARY

$V_R$	600 V
$V_F$ (typical) at 125 °C	1.00 V
$t_{rr}$ (typical)	65 ns
$I_{F(DC)}$ at $T_C$ per diode	200A at 90 °C

#### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	$V_R$		600	V
Maximum continuous forward current	$I_F$	$T_C = 90$ °C	200	A
Single pulse forward current	$I_{FSM}$	$T_J = 25$ °C	2000	
RMS isolation voltage, any terminal to case	$V_{ISOL}$	$t = 1$ minute	2500	V
Maximum power dissipation	$P_D$	$T_c = 25$ °C	710	W
Operating junction and storage temperature range	$T_J, T_{Stg}$		- 55 to 175	°C

## Nell High Power Products

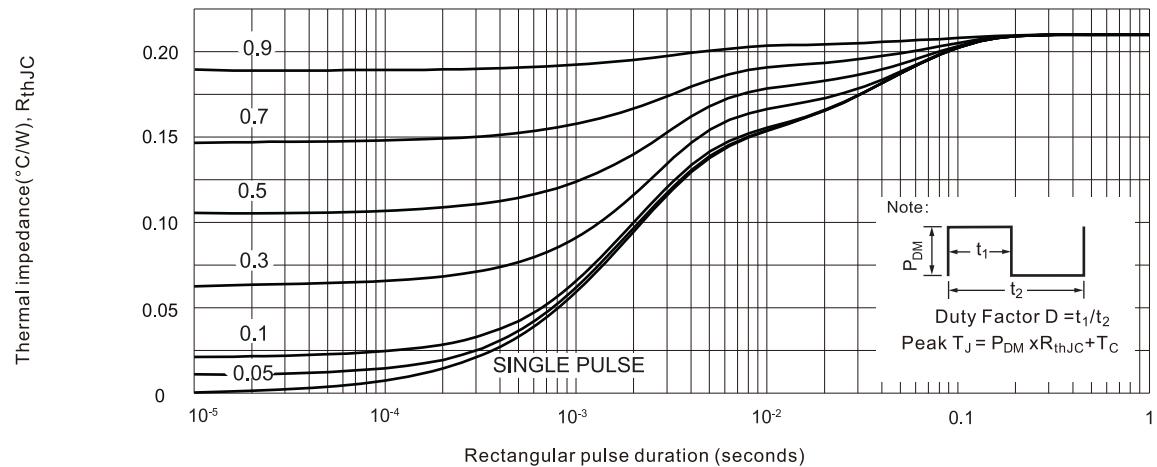
ELECTRICAL SPECIFICATIONS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	$V_{BR}$	$I_R = 100 \mu\text{A}$		600	-	-	V
Maximum forward voltage	$V_{FM}$	$I_F = 200 \text{ A}$		-	1.20	1.45	
		$I_F = 200 \text{ A}, T_J = 125^\circ\text{C}$		-	1.00	-	
Maximum reverse leakage current	$I_{RM}$	$V_R = V_R \text{ rated}$		-	0.5	5	$\mu\text{A}$
		$T_J = 125^\circ\text{C}, V_R = V_R \text{ rated}$		-	-	0.5	mA
Junction capacitance	$C_J$	$V_R = 200\text{V}$		400			pF

DYNAMIC RECOVERY CHARACTERISTICS PERLEG ( $T_J = 25^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 0.5\text{A}, I_R = 1.0\text{A}, I_{RR} = 250\text{mA}$ (RG#1 CKT)		-	105	130	ns
		$I_F = 1.0 \text{ A}, dI_F/dt = -200 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}, T_J = 25^\circ\text{C}$		-	65	-	
	$t_{rr1}$	$T_J = 25^\circ\text{C}$	$I_F = 200\text{A}$ $dI_F/dt = -200 \text{ A}/\mu\text{s}$ $V_R = 200 \text{ V}$	-	100	-	
Reverse recovery current	$I_{RRM1}$	$T_J = 25^\circ\text{C}$		-	13	-	A
	$I_{RRM2}$	$T_J = 125^\circ\text{C}$		-	19	-	
	$Q_{rr1}$	$T_J = 25^\circ\text{C}$		-	650	-	nC
Reverse recovery charge	$Q_{rr2}$	$T_J = 125^\circ\text{C}$		-	2850	-	

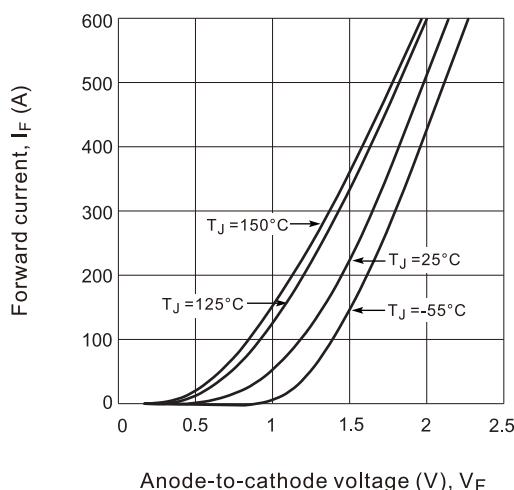
THERMAL - MECHANICAL SPECIFICATIONS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Junction to case, both legs conducting per module	$R_{thJC}$	-	-	0.21	$^\circ\text{C}/\text{W}$ (K/W)	
Case to sink, flat, greased surface	$R_{thCS}$	-	0.05	-		
Weight		-	30	-	g	
Mounting torque		-	1.3	-	Nm	

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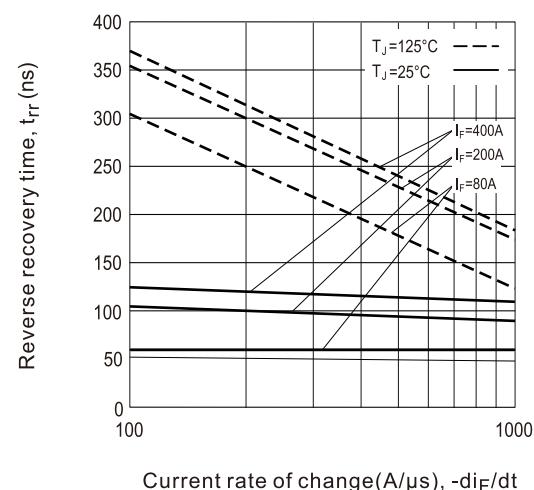
**Fig.1a Maximum effective transient thermal impedance, junction-to-case vs. pulse duration**



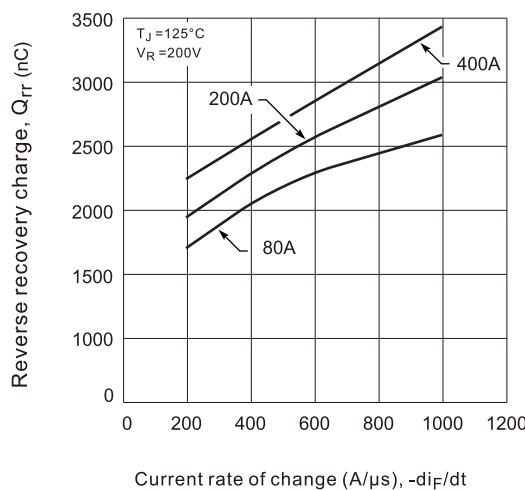
**Fig.2 Forward current vs. forward voltage**



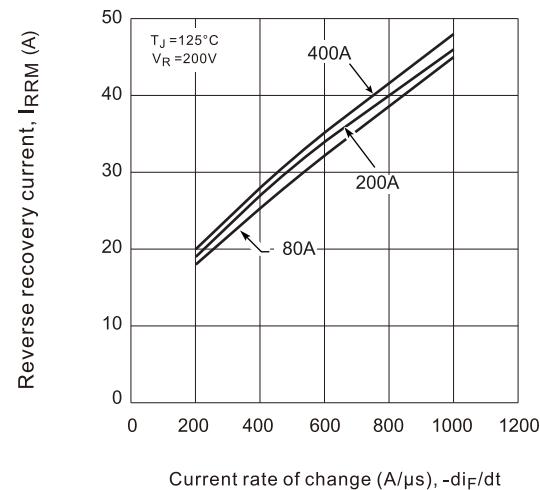
**Fig.3 Reverse recovery time vs. current rate of change**



**Fig.4 Reverse recovery charge vs. current rate of change**

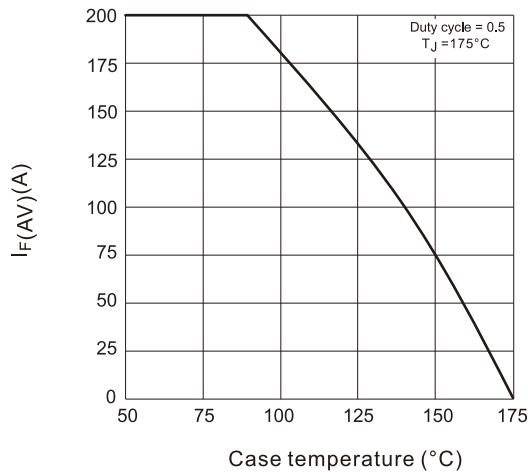


**Fig.5. Reverse recovery current vs. current rate of change**

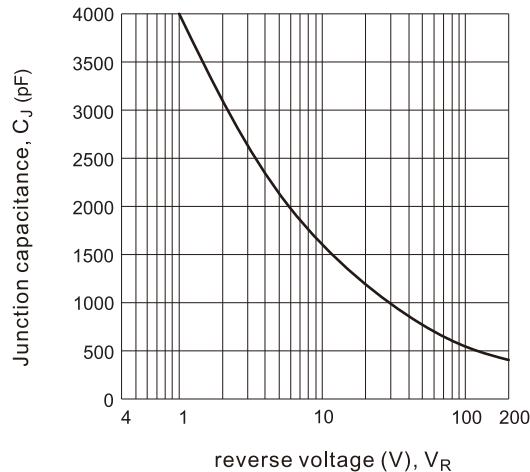


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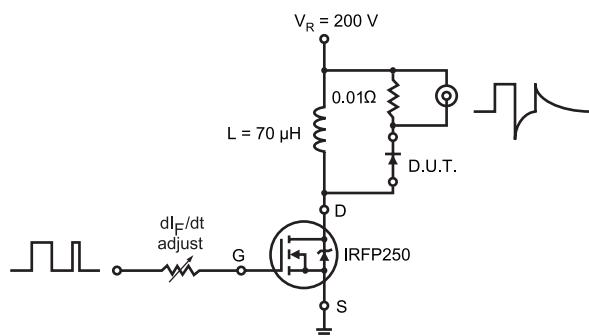
**Fig.6 Maximum average forward current vs. case temperature**



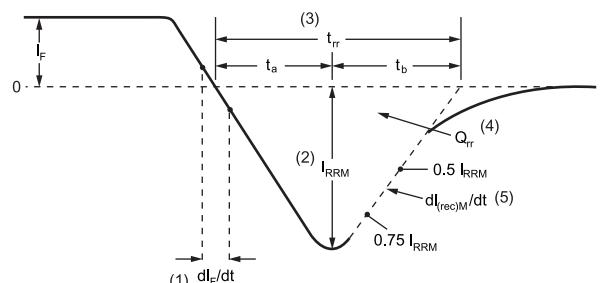
**Fig.7 Junction capacitance vs. reverse voltage**



**Fig.8 Reverse recovery parameter test circuit**



**Fig.9 Reverse recovery waveform and definitions**



(1)  $dI_F/dt$  - rate of change of current through zero crossing

(2)  $I_{RRM}$  - peak reverse recovery current

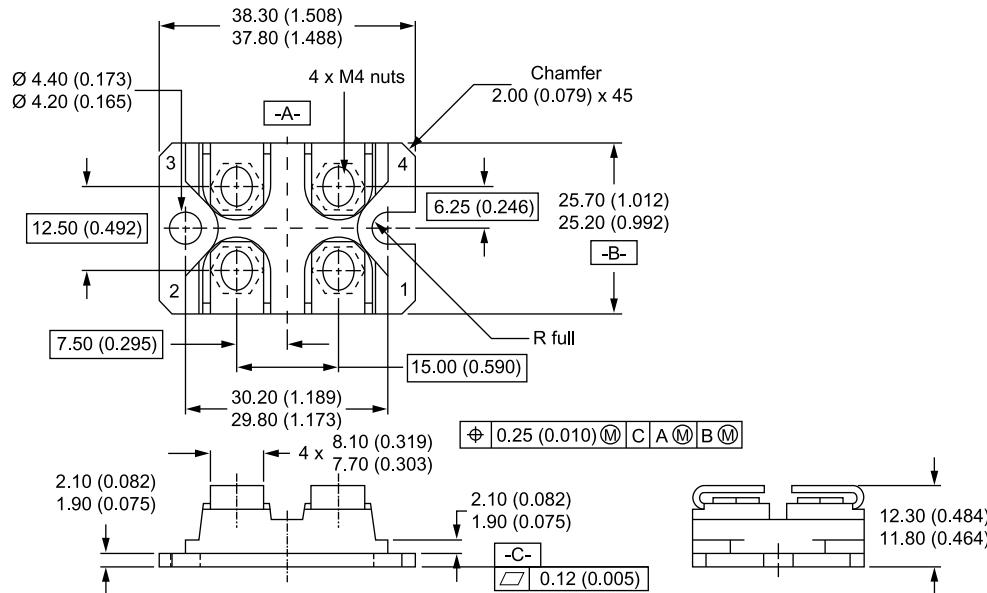
(3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current.

(4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

## SOT-227



All dimensions in millimeters (inches)

### Notes

- Dimensioning and tolerancing per ANSI Y14.5M-1982
- Controlling dimension: millimeter

## ORDERING INFORMATION TABLE

Device code	N	ST	200	F	06	E
	1	2	3	4	5	6

- |   |  |
|---|--|
| 1 | - Nell High Power Products                 |
| 2 | - Package indicator (SOT-227)              |
| 3 | - Current rating (200 = 200A)              |
| 4 | - F = FRED family, planar passivated chips |
| 5 | - Voltage rating (06 = 600 V)              |
| 6 | - Circuit type, Single Diode insulated     |